



Dual P-Channel 1.8 V (G-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)	Q _g (Typ.)			
	0.542 at V _{GS} = - 4.5 V	- 0.63				
- 8	0.798 at V _{GS} = - 2.5 V	- 0.52	10.5 nC			
	1.2 at V _{GS} = - 1.8 V	- 0.20				

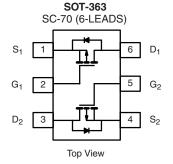
FEATURES

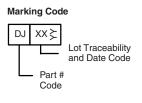
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC



APPLICATIONS

· Load Switch for Portable Devices





Ordering Information: Si1905BDH-T1-E3 (Lead (Pb)-free)

Si1905BDH-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V _{DS} - 8		V	
Gate-Source Voltage		V _{GS}	± 8	
	T _C = 25 °C		- 0.63	
Out in the County (T 450 00) 8 h	T _C = 70 °C		- 0.50	
Continuous Drain Current $(T_J = 150 ^{\circ}C)^{a, b}$	T _A = 25 °C	I _D	- 0.58 ^{a, b}	
	T _A = 70 °C		- 0.47 ^{a, b}	А
Pulsed Drain Current (10 μs Pulse Width)	I _{DM}	- 1.8	7	
a i a a a a a a a	T _C = 25 °C	1	- 0.30	
Continuous Source-Drain Diode Current ^{a, b}	T _A = 25 °C	I _S	- 0.25 ^{a, b}	
	T _C = 25 °C		0.357	
	T _C = 70 °C	В	0.228	
Maximum Power Dissipation ^{a, b}	T _A = 25 °C	P _D	0.301 ^{a, b}	W
	T _A = 70 °C		0.193 ^{a, b}	
Operating Junction and Storage Temperature Rar	T _J , T _{stg}	- 55 to 150		
Soldering Recommendations (Peak Temperature)		260	°C	

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Typical	Maximum	Unit			
Maniana lunation to Ambienta C	t ≤ 5 s	R _{thJA}	360	415	°C/W		
Maximum Junction-to-Ambient ^{a, c}	Steady State		400	460			
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	300	350			

Notes:

a. Surface mounted on 1" x 1" FR4 board.

b. t = 5 s.

c. Maximum under steady state conditions is 400 °C/W.

Si1905BDH

Vishay Siliconix



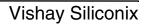
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 8			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$			7.15		1406	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = - 250 μA		- 1.66		mV/°C	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	- 0.45		- 1.0	V	
Gate-Source Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = -8 V			- 100	nA	
Zana Oaka Walka wa Busin Ouwani		V _{DS} = -8 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -8 V, V _{GS} = 0 V, T _J = 55 °C			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le 5 \text{ V}, V_{GS} = -4.5 \text{ V}$	- 1.8			Α	
	, ,	V _{GS} = - 4.5 V, I _D = - 0.58 A		0.450	0.542		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 2.5 V, I _D = - 0.47 A		0.655	0.798	Ω	
	` ,	V _{GS} = - 1.8 V, I _D = - 0.2 A		0.950	1.2		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 4 V, I _D = - 0.58 A		1.2		S	
Dynamic ^b				L	<u> </u>		
Input Capacitance	C _{iss}			62		pF	
Output Capacitance	C _{oss}	V _{DS} = - 4 V, V _{GS} = 0 V, f = 1 MHz		30			
Reverse Transfer Capacitance	C _{rss}			12			
Total Gate Charge	Q_g			1.0	1.5		
Gate-Source Charge	Q _{qs}	V _{DS} = - 4 V, V _{GS} = - 4.5 V, I _D = - 0.58 A		0.19		nC	
Gate-Drain Charge	Q _{gd}			0.20		1	
Gate Resistance	R _q	f = 1 MHz		6.3		Ω	
Turn-On Delay Time	t _{d(on)}			9	14		
Rise Time	t _r	$V_{DD} = -4 \text{ V}, R_{L} = 8.7 \Omega$		40	60		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -0.46 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$		50	75	- ns	
Fall Time	t _f	_		60	90		
Drain-Source Body Diode Characterist							
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			- 0.30		
Pulse Diode Forward Current	I _{SM}				- 1.8	A	
Body Diode Voltage	V _{SD}	I _S = - 1.4 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			25	38	ns	
Body Diode Reverse Recovery Charge	e O			7	11	nC	
Reverse Recovery Fall Time	t _a	$I_F = -1.4 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		9			
Reverse Recovery Rise Time	t _b			16		ns	

Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.

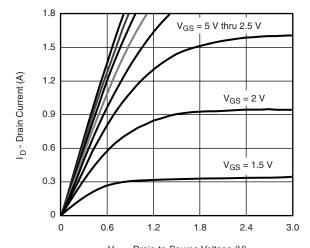
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





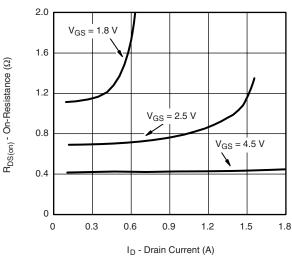


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

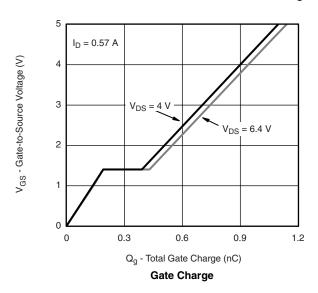


 $V_{\mbox{\footnotesize DS}}$ - Drain-to-Source Voltage (V)

Output Characteristics

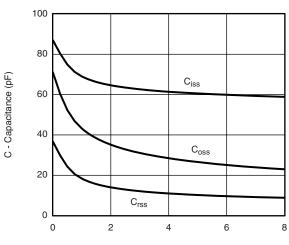


On-Resistance vs. Drain Current and Gate Voltage



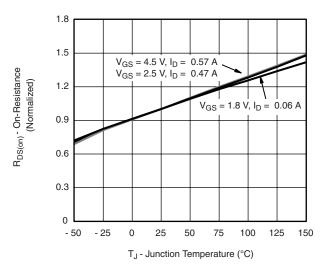
0.5 0.4 0.4 (Y) the brown of the properties o

V_{GS} - Gate-to-Source Voltage (V) **Transfer Characteristics**



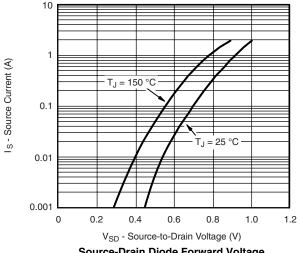
V_{DS} - Drain-to-Source Voltage (V)

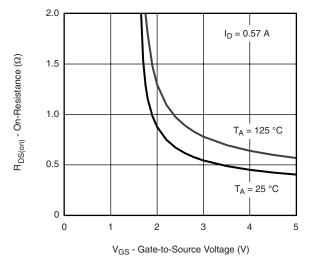
Capacitance



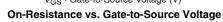
On-Resistance vs. Junction Temperature

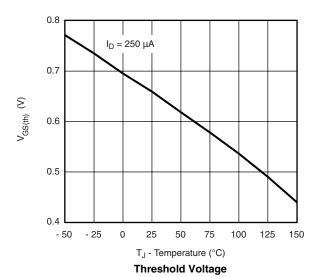
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

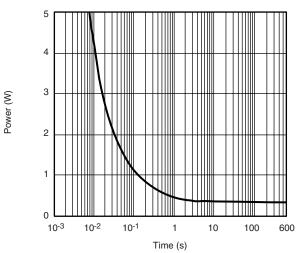




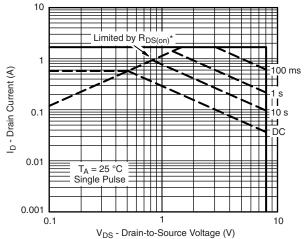
Source-Drain Diode Forward Voltage







Single Pulse Power, Junction-to-Ambient



* V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified

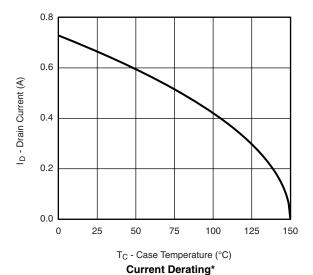
Safe Operating Area, Junction-to-Ambient

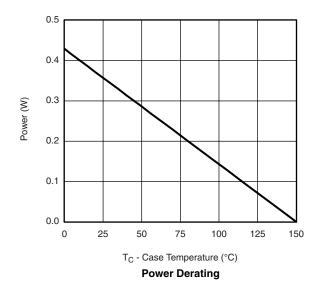






TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

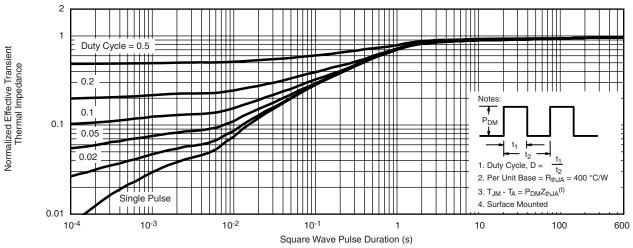




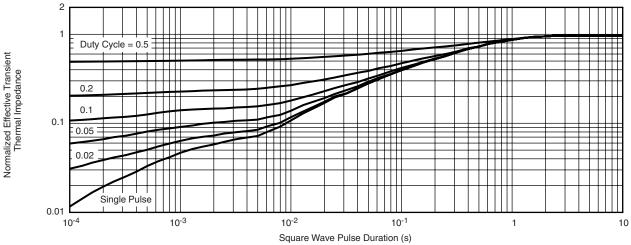
^{*} The power dissipation P_D is based on $T_{J(max)} = 150$ °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



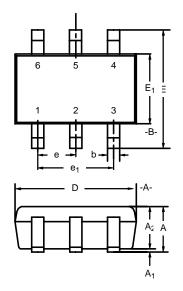
Normalized Thermal Transient Impedance, Junction-to-Case

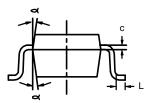
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SC-70: 6-LEADS





	MILLIMETERS			INCHES		
Dim	Min	Nom	Max	Min	Nom	Max
Α	0.90	_	1.10	0.035	_	0.043
A ₁	-	_	0.10	-	_	0.004
A ₂	0.80	_	1.00	0.031	_	0.039
b	0.15	_	0.30	0.006	_	0.012
С	0.10	-	0.25	0.004	-	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
Ε	1.80	2.10	2.40	0.071	0.083	0.094
E ₁	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65BSC			0.026BSC	;	
e ₁	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
کے	7°Nom				7°Nom	

DWG: 5550



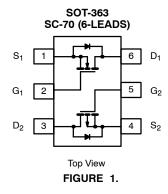
Dual-Channel LITTLE FOOT® 6-Pin SC-70 MOSFET Copper Leadframe Version Recommended Pad Pattern and Thermal Performance

INTRODUCTION

The new dual 6-pin SC-70 package with a copper leadframe enables improved on-resistance values and enhanced thermal performance as compared to the existing 3-pin and 6-pin packages with Alloy 42 leadframes. These devices are intended for small to medium load applications where a miniaturized package is required. Devices in this package come in a range of on-resistance values, in n-channel and p-channel versions. This technical note discusses pin-outs, package outlines, pad patterns, evaluation board layout, and thermal performance for the dual-channel version.

PIN-OUT

Figure 1 shows the pin-out description and Pin 1 identification for the dual-channel SC-70 device in the 6-pin configuration. Both n-and p-channel devices are available in this package — the drawing example below illustrates the p-channel device.



For package dimensions see outline drawing SC-70 (6-Leads) (http://www.vishay.com/doc?71154)

BASIC PAD PATTERNS

See Application Note 826, Recommended Minimum Pad Patterns With Outline Drawing Access for Vishay Siliconix MOSFETs, (http://www.vishay.com/doc?72286) for the SC-70 6-pin basic pad layout and dimensions. This pad pattern is sufficient for the low-power applications for which this package is intended. Increasing the drain pad pattern (Figure 2) yields a reduction in thermal resistance and is a preferred footprint.

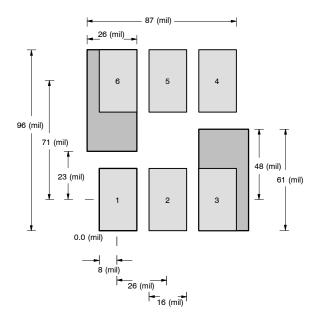


FIGURE 2. SC-70 (6 leads) Dual

EVALUATION BOARD FOR THE DUAL-CHANNEL SC70-6

The 6-pin SC-70 evaluation board (EVB) shown in Figure 3 measures 0.6 in. by 0.5 in. The copper pad traces are the same as described in the previous section, *Basic Pad Patterns*. The board allows for examination from the outer pins to the 6-pin DIP connections, permitting test sockets to be used in evaluation testing.

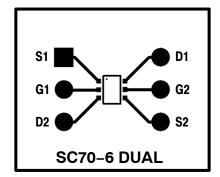
The thermal performance of the dual 6-pin SC-70 has been measured on the EVB, comparing both the copper and Alloy 42 leadframes. This test was then repeated using the 1-inch² PCB with dual-side copper coating.

A helpful way of displaying the thermal performance of the 6-pin SC-70 dual copper leadframe is to compare it to the traditional Alloy 42 version.

Document Number: 71405 www.vishay.com 12-Dec-03 1405



Front of Board SC70-6



Back of Board SC70-6

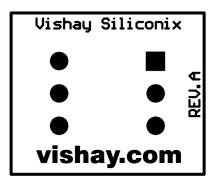


FIGURE 3.

THERMAL PERFORMANCE

Junction-to-Foot Thermal Resistance (the Package Performance)

Thermal performance for the dual SC-70 6-pin package is measured as junction-to-foot thermal resistance, in which the "foot" is the drain lead of the device as it connects with the body. The junction-to-foot thermal resistance for this device is typically 80°C/W, with a maximum thermal resistance of approximately 100°C/W. This data compares favorably with another compact, dual-channel package - the dual TSOP-6 which features a typical thermal resistance of 75°C/W and a maximum of 90°C/W.

Power Dissipation

The typical $R\theta_{JA}$ for the dual-channel 6-pin SC-70 with a copper leadframe is 224°C/W steady-state, compared to 413°C/W for the Alloy 42 version. All figures are based on the 1-inch² FR4 test board. The following example shows how the thermal resistance impacts power dissipation for the dual 6-pin SC-70 package at varying ambient temperatures.

Alloy 42 Leadframe

ALLOY 42 LEADFRAME				
Room Ambient 25 °C	Elevated Ambient 60 °C			
$P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$	$P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$			
$P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{413^{\circ}C/W}$	$P_{D} = \frac{150^{\circ}C - 60^{\circ}C}{413^{\circ}C/W}$			
$P_D = 303 \text{ mW}$	$P_D = 218 \text{ mW}$			

COOPER LEADFRAME					
Room Ambient 25 °C	Elevated Ambient 60 °C				
$P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$	$P_D = \frac{T_{J(max)} - T_A}{R\theta_{JA}}$				
$P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{224^{\circ}C/W}$	$P_{D} = \frac{150^{\circ}C - 60^{\circ}C}{224^{\circ}C/W}$				
$P_D = 558 \text{ mW}$	$P_D = 402 \text{mW}$				

Although they are intended for low-power applications, devices in the 6-pin SC-70 dual-channel configuration will handle power dissipation in excess of 0.5 W.

TESTING

To further aid the comparison of copper and Alloy 42 leadframes, Figures 4 and 5 illustrate the dual-channel 6-pin SC-70 thermal performance on two different board sizes and pad patterns. The measured steady-state values of $R\theta_{JA}$ for the dual 6-pin SC-70 with varying leadframes are as follows:

LITTLE FOOT 6-PIN SC-70					
	Alloy 42	Copper			
1) Minimum recommended pad pattern on the EVB board (see Figure 3).	518°C/W	344°C/W			
2) Industry standard 1-inch ² PCB with maximum copper both sides.	413°C/W	224°C/W			

The results indicate that designers can reduce thermal resistance (θJA) by 34% simply by using the copper leadframe device as opposed to the Alloy 42 version. In this example, a 174°C/W reduction was achieved without an increase in board area. If an increase in board size is feasible, a further 120°C/W reduction can be obtained by utilizing a 1-inch². PCB area.

The Dual copper leadframe versions have the following suffix:

Dual: Si19xxEDH Si15xxEDH Compl.:

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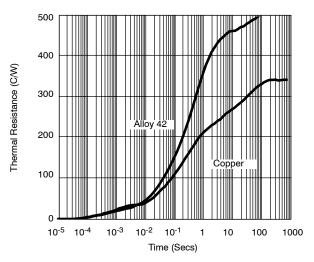


FIGURE 4. Dual SC70-6 Thermal Performance on EVB

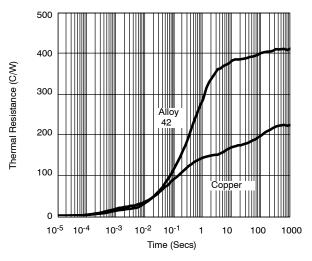
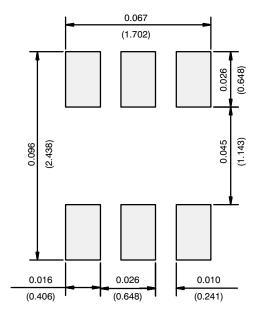


FIGURE 5. Dual SC70-6 Comparison on 1-inch² PCB



RECOMMENDED MINIMUM PADS FOR SC-70: 6-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



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Revision: 02-Oct-12 Document Number: 91000

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Contact Us:

> Address:

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd Minhang District, Shanghai , China

> Sales:

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

Customer Service :

Email service@ameya360.com

Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com